Supporting Information

Rationally Designed Hierarchical $ZnCo_2O_4/Ni(OH)_2$ Nanostructures for High-Performance Pseudocapacitor Electrodes

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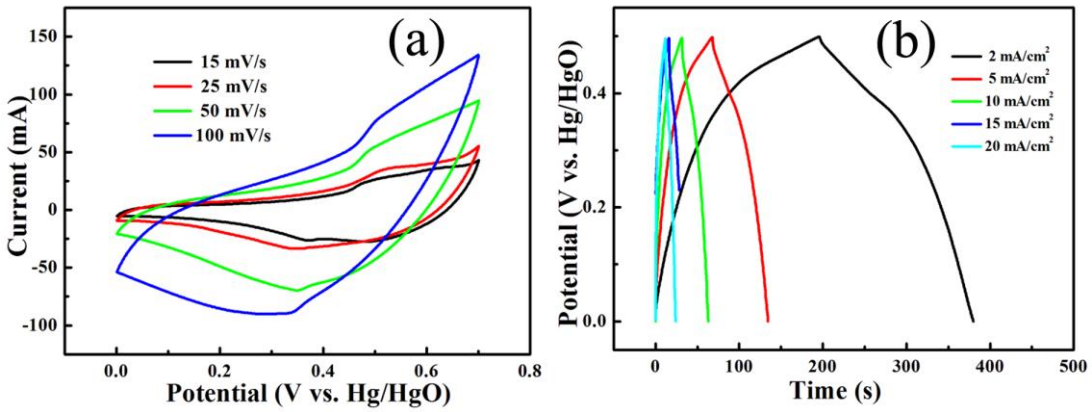

Figure S1 (a) CV and (b) galvanostatic charge-discharge curves of $ZnCo_2O_4$ nanowires at various scan rates and current densities.

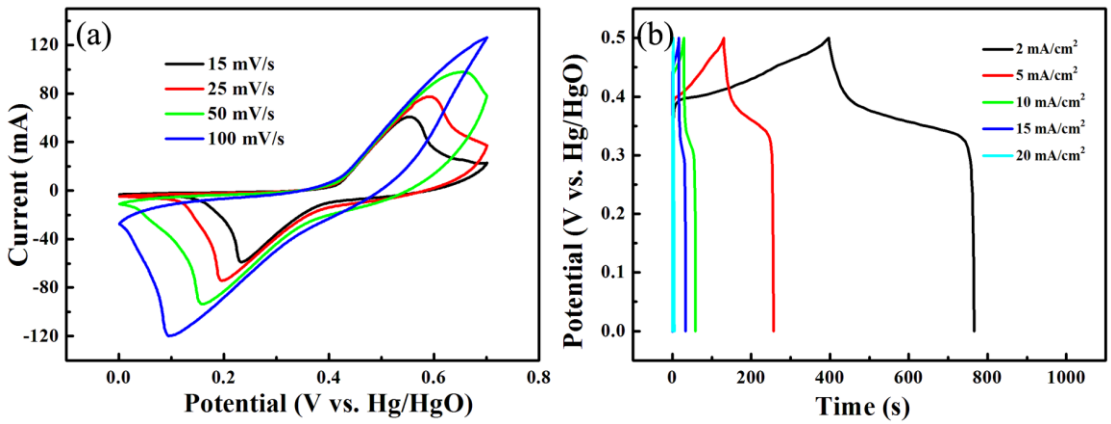

Figure S2 (a) CV and (b) galvanostatic charge-discharge curves of $Ni(OH)_2$ nanosheets at various scan rates and current densities.

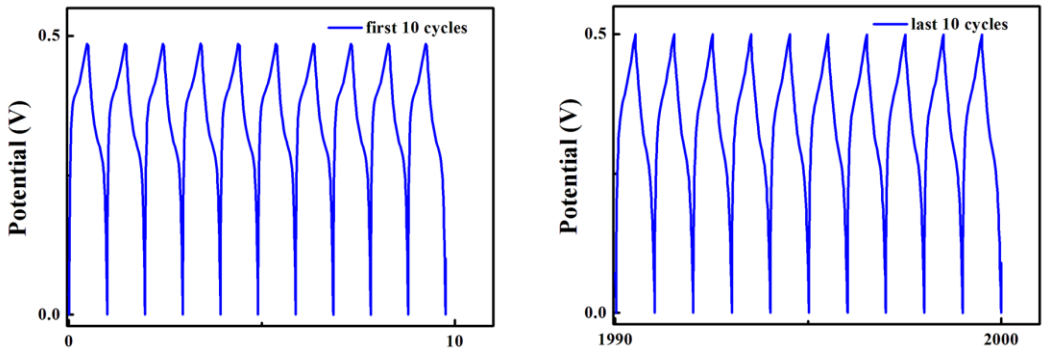

Figure S3 Galvanostatic charge/discharge cyclic curves of the first and last 10 cycles, respectively.

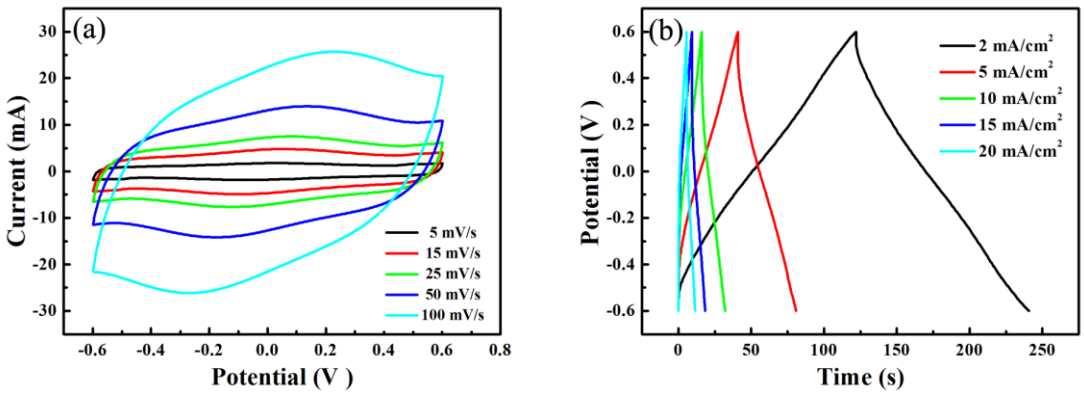

Figure S4 (a) CV and (b) galvanostatic charge-discharge curves of $ZnCo_2O_4$ nanowires at various scan rates and current densities in a two electrode system.

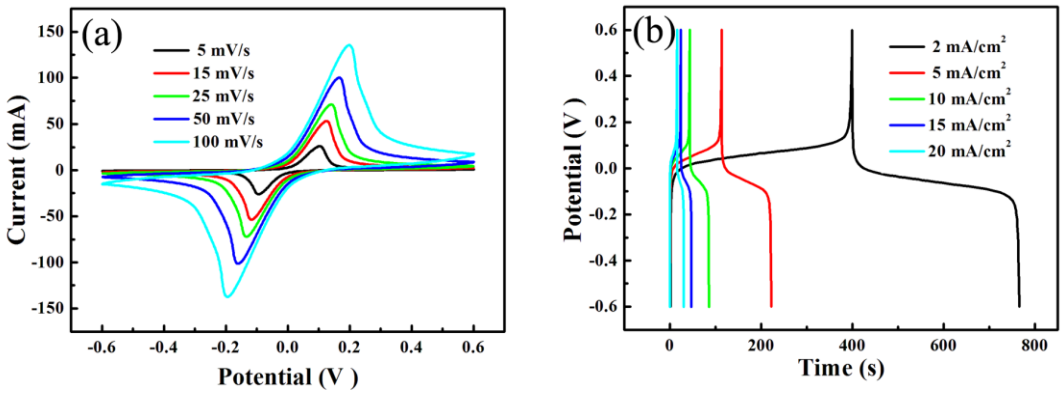

Figure S5 (a) CV and (b) galvanostatic charge-discharge curves of $Ni(OH)_2$ nanosheets at various scan rates and current densities in a two electrode system.